



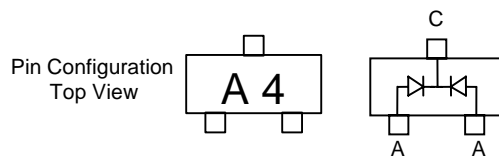
Micro Commercial Components  
 21201 Itasca Street Chatsworth  
 CA 91311  
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# BAV70

## 350mW 75 Volt Dual Switching Diode

### Features

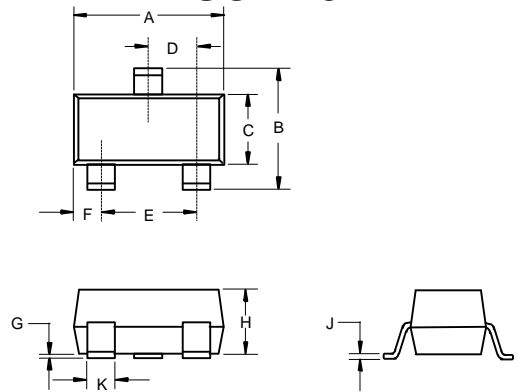
- Low Current Leakage
- Low Cost
- Small Outline Surface Mount Package



### Maximum Ratings

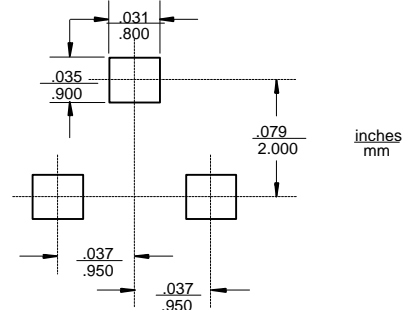
- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Maximum Thermal Resistance; 357 /W Junction To Ambient

### SOT-23



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.110	.120	2.80	3.04	
B	.083	.098	2.10	2.64	
C	.047	.055	1.20	1.40	
D	.035	.041	.89	1.03	
E	.070	.081	1.78	2.05	
F	.018	.024	.45	.60	
G	.0005	.0039	.013	.100	
H	.035	.044	.89	1.12	
J	.003	.007	.085	.180	
K	.015	.020	.37	.51	

### Suggested Solder Pad Layout



### Electrical Characteristics @ 25°C Unless Otherwise Specified

Reverse Voltage	$V_R$	75V	
Average Rectified Output Current	$I_O$	150mA	
Power Dissipation	$P_{TOT}$	350mW	
Peak Forward Surge Current	$I_{FSM}$	1.0A	$t=1s, Non-Repetitive$
Maximum Instantaneous Forward Voltage	$V_F$	855mV	$I_{FM} = 10mA;$ $T_J = 25^\circ C^*$
Maximum DC Reverse Current At Rated DC Blocking Voltage	$I_R$	2.5 $\mu A$ 50 $\mu A$	$V_R=75Volts$ $T_J = 25^\circ C$ $T_J = 150^\circ C$
Typical Junction Capacitance	$C_J$	2 pF	Measured at 1.0MHz, $V_R=0V$
Reverse Recovery Time	$T_{rr}$	4nS	$I_F=10mA$ $V_R = 0V$ $R_L=500\Omega$

\*Pulse test: Pulse width 300  $\mu sec$ , Duty cycle 2%

